RECTRON
SEMICONDUCTOR
TECHNICAL SPECIFICATION

EFM101L THRU EFM107L

SURFACE MOUNT GLASS PASSIVATED SUPER FAST SILICON RECTIFIER

VOLTAGE RANGE 50 to 600 Volts CURRENT 1.0 Ampere

NEW RELEASE

FEATURES

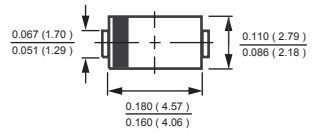
* Glass passivated device
* Ideal for surface mounted applications
* Low leakage current
* Metallurgically bonded construction
* Mounting position: Any
* Weight: 0.057 gram

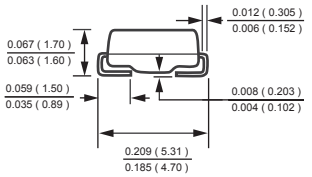
MECHANICAL DATA

* Epoxy : Device has UL flammability classification 94V-0



SMAL





Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

MAXIMUM RATINGS (@ TA=25 °C unless otherwise noted)

RATINGS	SYMBOL	EFM101L	EFM102L	EFM103L	EFM104L	EFM105L	EFM106L	EFM107L	UNITS
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	600	Volts
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	420	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	600	Volts
Maximum Average Forward Rectified Current at T_A = 55°C	I_O	1.0							Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	30							Amps
Typical Thermal Resistance (Note 4)	$R_{\theta JA}$	85							°C/W
	$R_{\theta JL}$	35							
Typical Junction Capacitance (Note 2)	C_J	15				10			pF
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to + 150							°C

ELECTRICAL CHARACTERISTICS(@TA=25 °C unless otherwise noted)

CHARACTERISTICS		SYMBOL	EFM101L	EFM102L	EFM103L	EFM104L	EFM105L	EFM106L	EFM107L	UNITS
Maximum Instantaneous Forward Voltage at 1.0A DC		V_F	0.95				1.25		1.50	Volts
Maximum DC Reverse Current at Rated DC Blocking Voltage	@T_A = 25°C	I_R	5.0							μAmps
	@T_A = 100°C		100							
Maximum Reverse Recovery Time (Note 1)		trr	35						50	nSec

NOTES : 1. Reverse Recovery Test Conditions: IF = 0.5A, IR = -1.0A, IRR = -0.25A

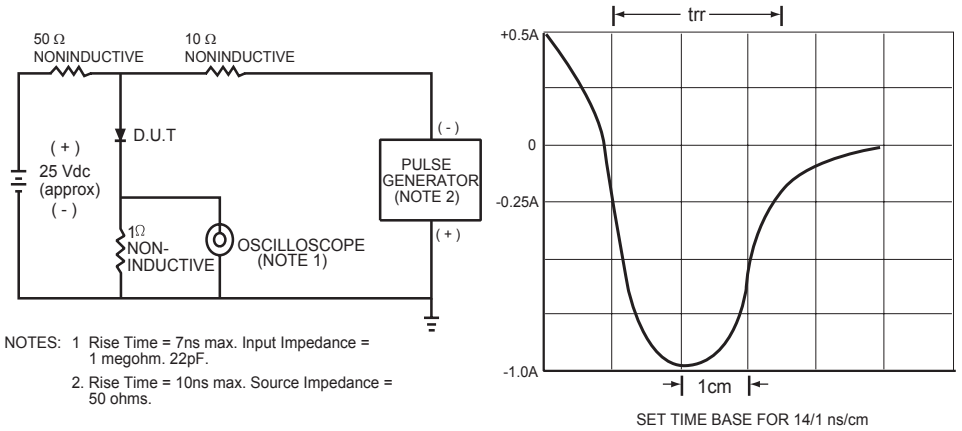
2. Measured at 1 MHz and applied reverse voltage of 4.0 volts

3. “Fully ROHS compliant”, “100% Sn plating (Pb-free)”.

4. Thermal Resistance : Mounted on PCB.

2006-12

RATING AND CHARACTERISTICS CURVES (EFM101L THRU EFM107L)



NOTES: 1 Rise Time = 7ns max. Input Impedance = 1 megohm. 22pF.

2. Rise Time = 10ns max. Source Impedance = 50 ohms.

SET TIME BASE FOR 14/1 ns/cm

FIG.1 TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

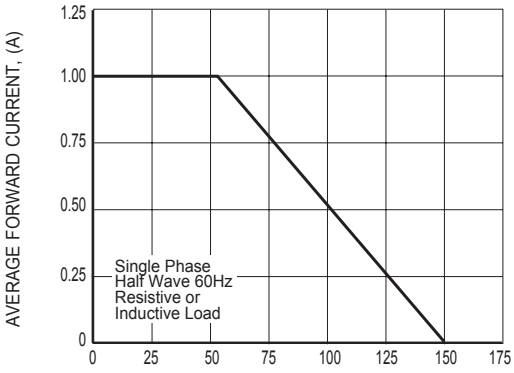


FIG.2 TYPICAL FORWARD CURRENT DERATING CURVE

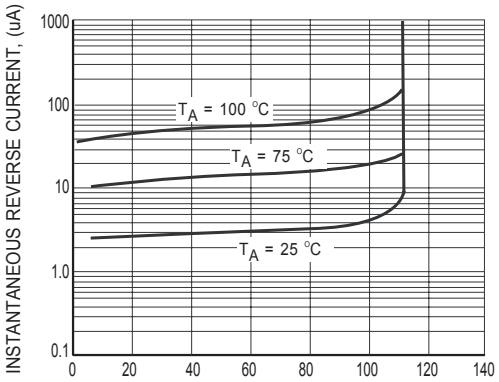


FIG.3 TYPICAL REVERSE CHARACTERISTICS

RATING AND CHARACTERISTICS CURVES (EFM101L THRU EFM107L)

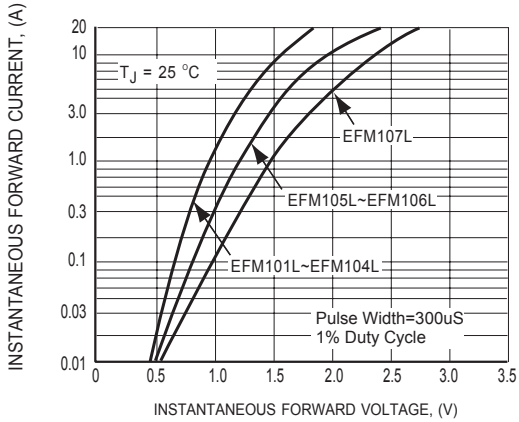


FIG.4 TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

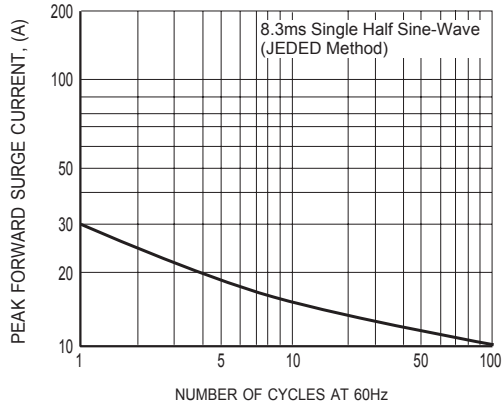


FIG.5 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

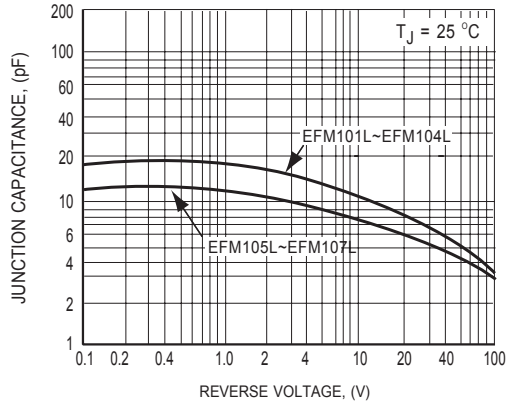
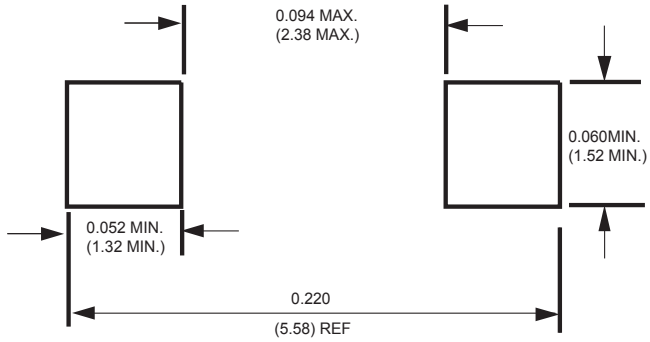


FIG.6 TYPICAL JUNCTION CAPACITANCE

Mounting Pad Layout



Dimensions in inches and (millimeters)

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